

## **KSD288**

# Power Regulator Low Frequency High Power Amplifier

- Collector-Base Voltage : V<sub>CBO</sub>=80V
- Collector Dissipation : P<sub>C</sub>=25W(T<sub>C</sub>=25°C)



1.Base 2.Collector 3.Emitter

## **NPN Epitaxial Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	80	V
V <sub>CEO</sub>	Collector-Emitter Voltage	55	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current	3	А
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	25	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_{C}=500\mu A, I_{E}=0$	80			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> =10mA,I <sub>B</sub> =0	55			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =500μA, I <sub>C</sub> =0	5			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB}=50V,I_{E}=0$			50	μΑ
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> =5V,I <sub>C</sub> =0.5A	40		240	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =1A, I <sub>B</sub> =0.1A			1	V

### **h**<sub>FE</sub> Classification

Classification	R	0	Y
h <sub>FE</sub>	40 ~ 80	70 ~ 140	120 ~ 240

## **Typical Characteristics**

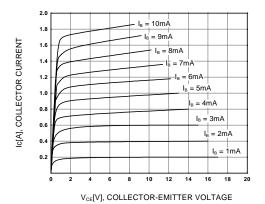


Figure 1. Static Characteristic

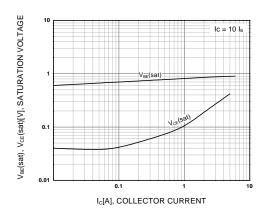


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

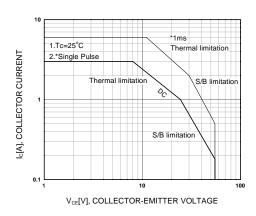


Figure 5. Safe Operating Area

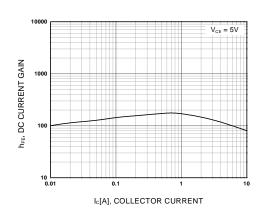


Figure 2. DC current Gain

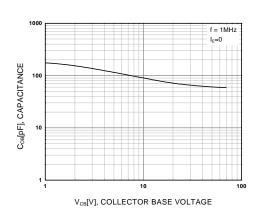


Figure 4. Collector Output Capacitance

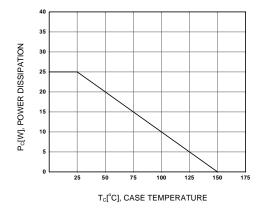
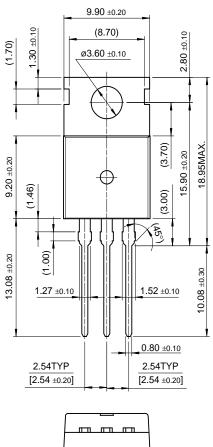


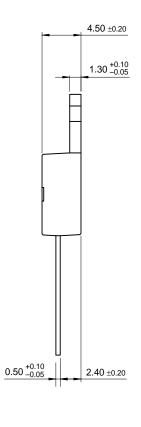
Figure 6. Power Derating

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## **Package Demensions**

## TO-220





10.00 ±0.20

Dimensions in Millimeters

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